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THE CHARGE STRUCUTRE AND INTERACTION MECHANISM ON In-DOPED SULPHUR SPINEL

Bae Soon Son, Sam Jin Kim, and Chul Sung Kim (Koomin University, Korea)

Synthesis of the sample was accomplished by the direct reaction of the high-purity elements Fe, Cr, In, and S in an evacuated quartz tube. The crystalline and magnetic properties were researched by x-ray diffraction (XRD), VSM, and Mössbauer spectroscopy. The XRD patterns for samples with nominal composition $FeIn_xCr_{2-x}S_4$ (x=0.1, 0.3) reveal that both samples are single phase with spinel structure. The crystal structure at room temperature is determined by the Rietveld method. It is found that the space group is Fd3m and resulting lattice parameters are a_0 =10.029, 10.093 Å, for the x=0.1 and 0.3, respectively. The Néel temperature is decreased with increasing non magnetic In substitution as consequence of reduction of superexchange interaction for increased lattice size. The Mössbauer spectra were measured from 4.2 K to room temperature. The asymmetric line broadening is observed for the sample $FeIn_xCr_{2-x}S_4$ and considered to be dynamic Jahn-Teller relaxation. The charge state of Fe ions is ferrous in character.

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☐Oral ■Poster ☐Invited Talk

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Corresponding Author:

Chul Sung Kim

861-1, Chongnung-Dong, Department of Physics, Kookmin University, Seoul 136-702, Korea

E-mail: cskim@phys.kookmin.ac.kr

Phon:+82-2-910-4752 Fax:+82-2-910-5170